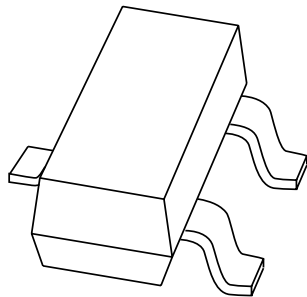


DATA SHEET



BCW29; BCW30 PNP general purpose transistors

Product specification
Supersedes data of 1997 Sep 03

1999 Apr 13

PNP general purpose transistors

BCW29; BCW30

FEATURES

- Low current (max. 100 mA)
- Low voltage (max. 32 V).

APPLICATIONS

- General purpose switching and amplification.

DESCRIPTION

PNP transistor in a SOT23 plastic package.
NPN complements: BCW31 and BCW32.

MARKING

| TYPE NUMBER | MARKING CODE ⁽¹⁾ |
|-------------|-----------------------------|
| BCW29 | C1* |
| BCW30 | C2* |

Note

- * = p : Made in Hong Kong.
* = t : Made in Malaysia.

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | base |
| 2 | emitter |
| 3 | collector |

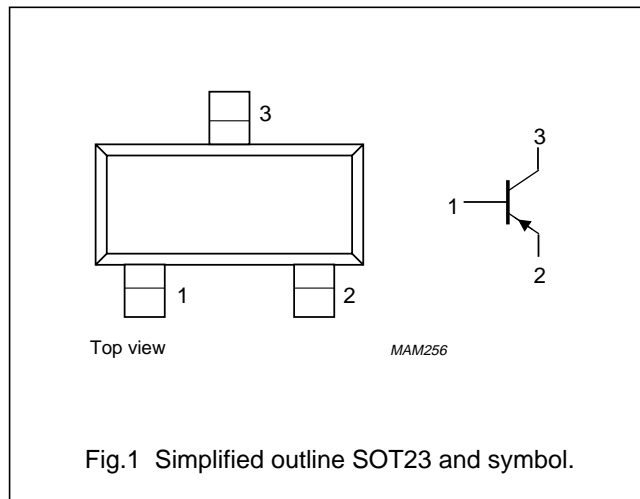


Fig.1 Simplified outline SOT23 and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|-----------|-------------------------------|--------------------------|------|------|------|
| V_{CBO} | collector-base voltage | open emitter | - | -32 | V |
| V_{CEO} | collector-emitter voltage | open base; $I_C = -2$ mA | - | -32 | V |
| V_{EBO} | emitter-base voltage | open collector | - | -5 | V |
| I_C | collector current (DC) | | - | -100 | mA |
| I_{CM} | peak collector current | | - | -200 | mA |
| I_{BM} | peak base current | | - | -200 | mA |
| P_{tot} | total power dissipation | $T_{amb} \leq 25$ °C | - | 250 | mW |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| T_j | junction temperature | | - | 150 | °C |
| T_{amb} | operating ambient temperature | | -65 | +150 | °C |

PNP general purpose transistors

BCW29; BCW30

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|---------------|---|------------|-------|------|
| $R_{th\ j-a}$ | thermal resistance from junction to ambient | note 1 | 500 | K/W |

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

$T_j = 25\text{ °C}$ unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-------------|--------------------------------------|---|------|------|------|---------------|
| I_{CBO} | collector cut-off current | $I_E = 0; V_{CB} = -32\text{ V}$ | – | – | –100 | nA |
| | | $I_E = 0; V_{CB} = -32\text{ V}; T_j = 100\text{ °C}$ | – | – | –10 | μA |
| I_{EBO} | emitter cut-off current | $I_C = 0; V_{EB} = -5\text{ V}$ | – | – | –100 | nA |
| h_{FE} | DC current gain BCW29 BCW30 | $I_C = -10\text{ }\mu\text{A}; V_{CE} = -5\text{ V}$ | – | 90 | – | |
| | | | – | 150 | – | |
| | DC current gain BCW29 BCW30 | $I_C = -2\text{ mA}; V_{CE} = -5\text{ V}$ | 120 | – | 260 | |
| | | | 215 | – | 500 | |
| V_{CEsat} | collector-emitter saturation voltage | $I_C = -10\text{ mA}; I_B = -0.5\text{ mA}$ | – | –80 | –300 | mV |
| | | $I_C = -50\text{ mA}; I_B = -2.5\text{ mA}$ | – | –150 | – | mV |
| V_{BEsat} | base-emitter saturation voltage | $I_C = -10\text{ mA}; I_B = -0.5\text{ mA}$ | – | –720 | – | mV |
| | | $I_C = -50\text{ mA}; I_B = -2.5\text{ mA}$ | – | –810 | – | mV |
| V_{BE} | base-emitter voltage | $I_C = -2\text{ mA}; V_{CE} = -5\text{ V}$ | –600 | – | –750 | mV |
| C_c | collector capacitance | $I_E = i_e = 0; V_{CB} = -10\text{ V}; f = 1\text{ MHz}$ | – | 4.5 | – | pF |
| f_T | transition frequency | $I_C = -10\text{ mA}; V_{CE} = -5\text{ V}; f = 100\text{ MHz}$ | 100 | – | – | MHz |
| F | noise figure | $I_C = -200\text{ }\mu\text{A}; V_{CE} = -5\text{ V}; R_S = 2\text{ k}\Omega;$ $f = 1\text{ kHz}; B = 200\text{ Hz}$ | – | – | 10 | dB |

PNP general purpose transistors

BCW29; BCW30

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



DIMENSIONS (mm are the original dimensions)

| UNIT | A | A ₁ max. | b _p | c | D | E | e | e ₁ | H _E | L _p | Q | v | w |
|------|------------|------------------------|----------------|--------------|------------|------------|-----|----------------|----------------|----------------|--------------|-----|-----|
| mm | 1.1 0.9 | 0.1 | 0.48 0.38 | 0.15 0.09 | 3.0 2.8 | 1.4 1.2 | 1.9 | 0.95 | 2.5 2.1 | 0.45 0.15 | 0.55 0.45 | 0.2 | 0.1 |

| OUTLINE VERSION | REFERENCES | | | | EUROPEAN PROJECTION | ISSUE DATE |
|-----------------|------------|-------|------|--|---------------------|------------|
| | IEC | JEDEC | EIAJ | | | |
| SOT23 | | | | | | 97-02-28 |

PNP general purpose transistors

BCW29; BCW30

DEFINITIONS

| | |
|---|---|
| Data sheet status | |
| Objective specification | This data sheet contains target or goal specifications for product development. |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification | This data sheet contains final product specifications. |
| Limiting values | |
| Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | |
| Application information | |
| Where application information is given, it is advisory and does not form part of the specification. | |

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PNP general purpose transistors

BCW29; BCW30

NOTES

PNP general purpose transistors

BCW29; BCW30

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Printed in The Netherlands

115002/00/04/pp8

Date of release: 1999 Apr 13

Document order number: 9397 750 05621

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